74LVTH322245

3.3 V 32-bit bus transceiver with 30 Ω termination resistors; 3-state

Rev. 01 — 24 January 2007

Product data sheet

1. General description

The 74LVTH322245 is a high-performance BiCMOS product designed for V_{CC} operation at 3.3 V. The 74LVTH322245 is designed with 30 Ω series resistance in both the HIGH and LOW states of the output. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus receivers/transmitters. The 74LVTH322245 is a 32-bit transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions. The device features four output enable $(n\overline{OE})$ inputs for easy cascading and four send/receive (nDIR) inputs for direction control. Pin $n\overline{OE}$ controls the outputs so that the buses are effectively isolated. Bus hold on data inputs eliminates the need for external pull-up resistors to hold unused inputs.

2. Features

- 32-bit bidirectional bus interface
- 3-state buffers
- Output capability: +12 mA and -12 mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- Bus hold data inputs eliminate need for external pull-up resistors to hold unused inputs
- Live insertion and extraction permitted
- \blacksquare Outputs include series resistance of 30 Ω making external resistors unnecessary
- Power-up 3-state
- No bus current loading when output is tied to 5 V bus
- Latch-up protection:
 - ◆ JESD78 Class II level A exceeds 500 mA
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V

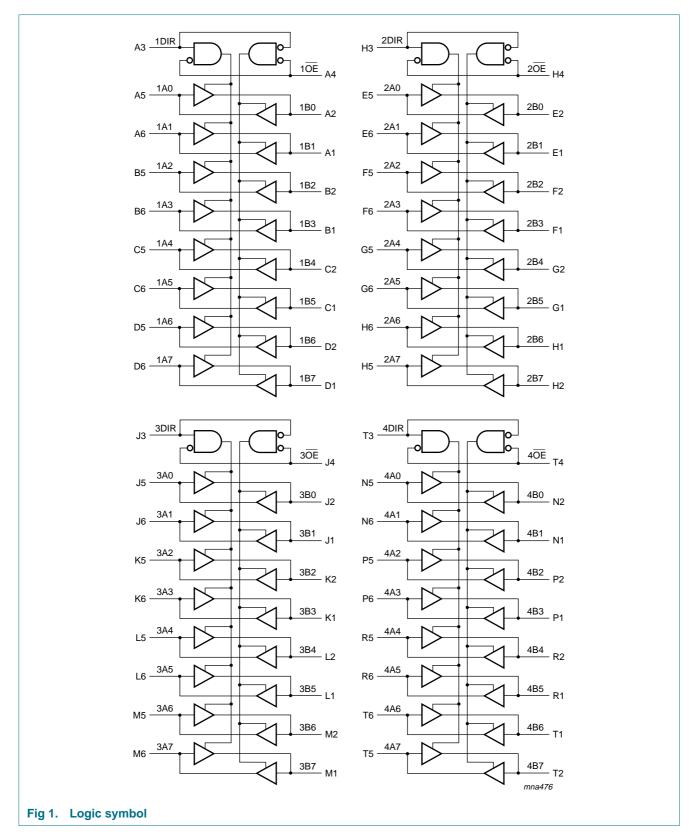
3. Ordering information

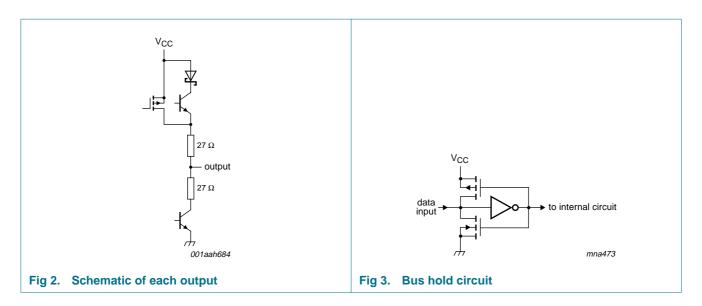
Table 1. Ordering information

Type number	Package					
	Temperature range	Name	Description	Version		
74LVTH322245EC	–40 °C to +125 °C	LFBGA96	plastic low profile fine-pitch ball grid array package; 96 balls; body $13.5 \times 5.5 \times 1.05$ mm	SOT536-1		



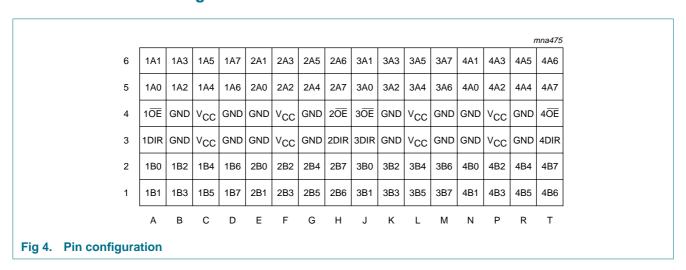
4. Functional diagram





5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Ball	Description
nDIR (n = 1 to 4)	A3, H3, J3, T3	direction control
$n\overline{OE}$ (n = 1 to 4)	A4, H4, J4, T4	output enable input (active LOW)
1A[0:7]	A5, A6, B5, B6, C5, C6, D5, D6	input or output
1B[0:7]	A2, A1, B2, B1, C2, C1, D2, D1	input or output
2A[0:7]	E5, E6, F5, F6, G5, G6, H6, H5	input or output
2B[0:7]	E2, E1, F2, F1, G2, G1, H1, H2	input or output
3A[0:7]	J5, J6, K5, K6, L5, L6, M5, M6	input or output
3B[0:7]	J2, J1, K2, K1, L2, L1, M2, M1	input or output
74LVTH322245_1		© NXP B.V. 2008. All rights reserve

Table 2. Pin description ... continued

Symbol	Ball	Description
4A[0:7]	N5, N6, P5, P6, R5, R6, T6, T5	input or output
4B[0:7]	N2, N1, P2, P1, R2, R1, T1, T2	input or output
GND	B3, B4, D3, D4, E3, E4, G3, G4, K3, K4, M3, M4, N3, N4, R3, R4	ground (0 V)
V _{CC}	C3, C4, F3, F4, L3, L4, P3, P4	supply voltage

6. Functional description

Table 3. Function selection[1]

		Input/output		
nOE	nDIR	nAn	nBn	
L	L	nAn = nBn	inputs	
L	Н	inputs	nBn = nAn	
Н	X	Z	Z	

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V)[1][2]

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+4.6	V
V_{I}	input voltage		<u>[3]</u> −0.5	+7.0	V
Vo	output voltage	output in OFF or HIGH-state	<u>[3]</u> −0.5	+7.0	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
I_{OK}	output clamping current	V _O < 0 V	-50	-	mA
I _O	output current	output in LOW-state	-	128	mA
		output in HIGH-state	-64	-	mA
T _{stg}	storage temperature		-65	+150	°C
T_j	junction temperature		-	150	°C

^[1] Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond indicated under Section 8 "Recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

^[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

^[3] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

Recommended operating conditions

Table 5. **Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		2.7	-	3.6	V
V_{I}	input voltage		0	-	5.5	V
I_{OH}	HIGH-level output current		-12	-	-	mA
I_{OL}	LOW-level output current		-	-	12	mA
T_{amb}	ambient temperature	in free air	-40	-	+85	°C
$\Delta t/\Delta V$	input transition rise and fall rate	outputs enabled	-	-	10	ns/V
P _{tot}	total power dissipation		<u>[1]</u> _	-	1000	mW

^[1] Above 70 $^{\circ}$ C the value of P_{tot} derates linearly with 1.8 mW/K.

Static characteristics

Table 6. **Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +85 °C[1]					
V _{IK}	input clamping voltage	$V_{CC} = 2.7 \text{ V}; I_{IK} = -18 \text{ mA}$	-1.2	-0.85	-	V
V _{IH}	HIGH-level input voltage		2.0	-	-	V
V _{IL}	LOW-level input voltage		-	-	8.0	V
V _{OH}	HIGH-level output voltage	$V_{CC} = 3.0 \text{ V}; I_{OH} = -12 \text{ mA}$	2.0	2.5	-	V
V _{OL}	LOW-level output voltage	$V_{CC} = 3.0 \text{ V}; I_{OL} = 12 \text{ mA}$	-	0.3	8.0	V
Iı	input leakage current	control pins				
		V_{CC} = 3.6 V; V_I = V_{CC} or GND	-	0.1	±1	μΑ
		$V_{CC} = 0 \text{ V or } 3.6 \text{ V; } V_{I} = 5.5 \text{ V}$	-	0.1	10	μΑ
		input/output data pins; V _{CC} = 3.6 V	[2]			
		$V_I = V_{CC}$	-	0.5	10	μΑ
		$V_I = 0 V$	-5	-0.1	-	μΑ
l _{OFF}	power-off leakage current	$V_{CC} = 0 \text{ V}$; $V_I \text{ or } V_O = 0 \text{ V to } 4.5 \text{ V}$	-	0.1	±100	μΑ
I _{LO}	output leakage current	output HIGH; $V_O = 5.5 \text{ V}$; $V_{CC} = 3.0 \text{ V}$	-	75	125	μΑ
I _{O(pu/pd)}	power-up/power-down output current	$V_{CC} \le 1.2 \text{ V}; V_O = 0.5 \text{ V to } V_{CC};$ $V_I = \text{GND or } V_{CC}; n\overline{OE} = \text{don't care}$	[4] _	40	±100	μΑ
I _{BHL}	bus hold LOW current	$V_{CC} = 3 \text{ V}; V_{I} = 0.8 \text{ V}$	75	135	-	μΑ
I _{BHH}	bus hold HIGH current	$V_{CC} = 3 \text{ V}; V_{I} = 2.0 \text{ V}$	-	-135	-75	μΑ
I _{BHLO}	bus hold LOW overdrive current	$V_{CC} = 0 \text{ V to } 3.6 \text{ V}; V_{I} = 3.6 \text{ V}$	[<u>3</u>] 500	-	-	μΑ
I _{BHHO}	bus hold HIGH overdrive current	$V_{CC} = 0 \text{ V to } 3.6 \text{ V}; V_{I} = 3.6 \text{ V}$	[3] -	-	-500	μΑ
I _{CC}	supply current	$V_{CC} = 3.6 \text{ V}$; $V_I = \text{GND or } V_{CC}$; $I_O = 0 \text{ A}$				
		outputs HIGH	-	0.14	0.24	mΑ
		outputs LOW	-	8.4	12	mA
		outputs disabled	[5] _	0.14	0.24	mA
4LVTH322245_	1			@ N	IXP B.V. 2008.	All rights rose

 Table 6.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
ΔI_{CC}	additional supply current	per input pin; $V_{CC} = 3 \text{ V to } 3.6 \text{ V}$; one input at $V_{CC} - 0.6 \text{ V}$; other inputs at V_{CC} or GND	<u>[6]</u> -	0.1	0.2	mA
Cı	input capacitance	control pins; $V_0 = 0 \text{ V or } 3.0 \text{ V}$	-	3	-	pF
C _{I/O}	input/output capacitance	input/output data pins; outputs disabled; V_{CC} = 3.6 V; I_{O} = 0 A; V_{I} = GND or V_{CC}	-	9	-	pF

^[1] All typical values are at V_{CC} = 3.3 V and T_{amb} = 25 °C unless otherwise specified.

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for load circuit see Figure 7.

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
$T_{amb} = -4$	0 °C to +85 °C					
t _{PLH}	LOW to HIGH propagation delay	nAn to nBn or nBn to nAn; see Figure 5				
		V _{CC} = 2.7 V	-	-	3.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	2.5	3.5	ns
t _{PHL} HIGH to LOW propagation delay		nAn to nBn or nBn to nAn; see Figure 5				
		V _{CC} = 2.7 V	-	-	3.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	2.2	3.5	ns
t _{PZH} OFF-state to H	OFF-state to HIGH propagation delay	nOE to nAn or nBn; see Figure 6				
		V _{CC} = 2.7 V	-	-	6.4	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	1.5	3.5	5.3	ns
t_{PZL}	OFF-state to LOW propagation delay	nOE to nAn or nBn; see Figure 6				
		V _{CC} = 2.7 V	-	-	5.0	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	1.5	3.2	4.4	ns
t_{PHZ}	HIGH to OFF-state propagation delay	nOE to nAn or nBn; see Figure 6				
		V _{CC} = 2.7 V	-	-	5.1	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	1.5	3.5	4.8	ns
t _{PLZ}	LOW to OFF-state propagation delay	nOE to nAn or nBn; see Figure 6				
		V _{CC} = 2.7 V	-	-	5.9	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	1.5	4.3	6.7	ns

^[1] All typical values are at V_{CC} = 3.3 V and T_{amb} = 25 °C.

74LVTH322245_1 © NXP B.V. 2008. All rights reserved.

^[2] Unused pins at V_{CC} or GND.

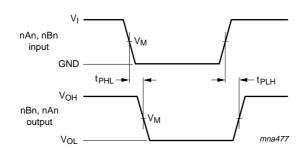
^[3] This is the bus-hold overdrive current required to force the input to the opposite logic state.

^[4] This parameter is valid for any V_{CC} between 0 V and 1.2 V with a transition time of up to 10 ms. From V_{CC} = 1.2 V to V_{CC} = 3.3 V \pm 0.3 V a transition time of 100 μ s is permitted. This parameter is valid for T_{amb} = 25 °C only.

^[5] I_{CC} is measured with outputs pulled to V_{CC} or GND.

^[6] This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.

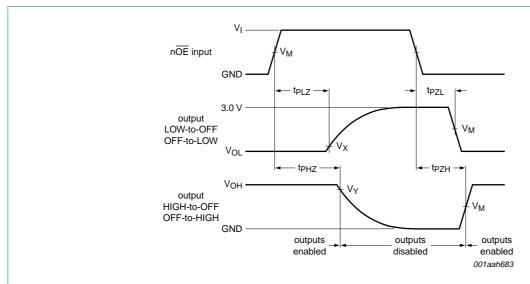
11. Waveforms



Measurement points are given in Table 8.

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 5. Input to output propagation delays



Measurement points are given in Table 8.

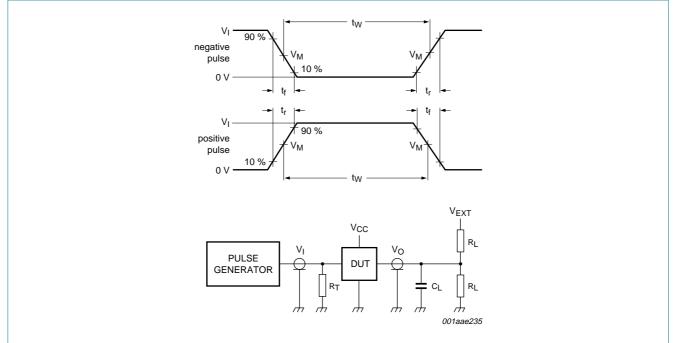
 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 6. enable and disable times

Table 8. Measurement points

Supply voltage	Input	Output		
V _{CC}	V _M	V _M	V_X	V _Y
2.7 V to 3.6 V	1.5 V	1.5 V	V _{OL} + 0.3 V	V _{OH} – 0.3 V

74LVTH322245_1 © NXP B.V. 2008. All rights reserved.



Test data is given in Table 9.

Definitions test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 7. Load circuitry for switching times

Table 9. Test data

Input			Load V _{EXT}					
V _I	f _i	t _W	t _r , t _f	R _L	CL	t _{PHZ} , t _{PZH}	t _{PLZ} , t _{PZL}	t _{PLH} , t _{PHL}
2.7 V	≤ 10 MHz	500 ns	≤ 2.5 ns	500 Ω	50 pF	GND	6 V	open

12. Package outline

LFBGA96: plastic low profile fine-pitch ball grid array package; 96 balls; body 13.5 x 5.5 x 1.05 mm SOT536-1

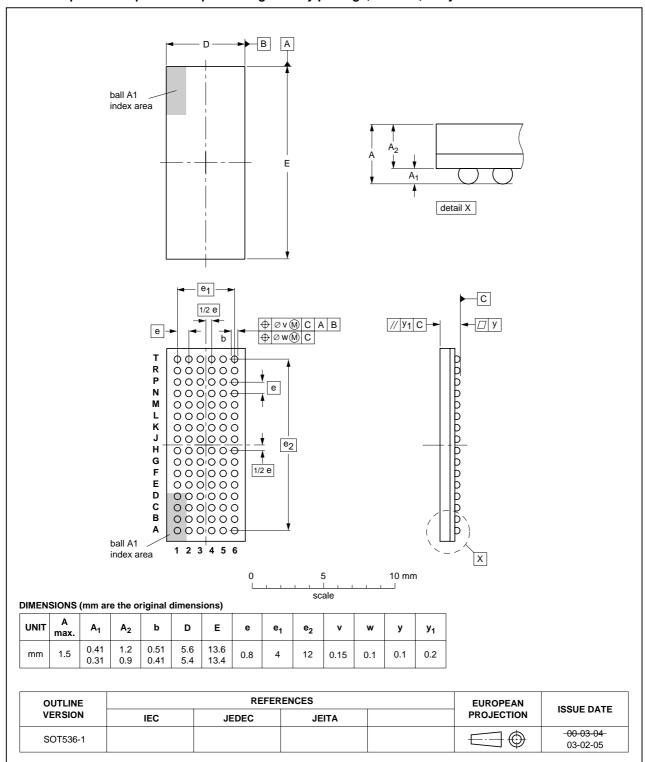


Fig 8. Package outline SOT536-1 (LFBGA96)

74LVTH322245_1 © NXP B.V. 2008. All rights reserved.

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
BiCMOS	Bipolar Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVTH322245_1	20080124	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

15.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

15.3 Disclaimers

General — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental

damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

15.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

16. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

17. Contents

1	General description
2	Features
3	Ordering information
4	Functional diagram 2
5	Pinning information 3
5.1	Pinning
5.2	Pin description
6	Functional description 4
7	Limiting values 4
8	Recommended operating conditions 5
9	Static characteristics 5
10	Dynamic characteristics 6
11	Waveforms
12	Package outline 9
13	Abbreviations
14	Revision history
15	Legal information
15.1	Data sheet status
15.2	Definitions11
15.3	Disclaimers
15.4	Trademarks11
16	Contact information 11
17	Contents 12

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

